NSN 5962-01-374-8572

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-374-8572

View Offiline at https://derobasegroup.com/nsi//0302-01-074-0372
Body Length:
Between 0.930 inches and 0.970 inches
Body Width:
Between 0.245 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.175 inches
Maximum Power Dissipation Rating:
490.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmed and bidirectional and w/disable and w/enable and ultraviolet erasable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
15 input
Current Rating Per Characteristic:
70.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
And-or invert gate array
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Capitance Rating Per Characteristic:
7.00 input picofarads and 7.00 output picofarads
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:

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Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

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